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FCH47N60F_F085

N-Channel MOSFET

600V, 47A, 75mΩ

Features

- Typ $r_{DS(on)}$ = 66mΩ at $V_{GS} = 10V$, $I_D = 47A$
- Typ $Q_{g(tot)}$ = 190nC at $V_{GS} = 10V$, $I_D = 47A$
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Description

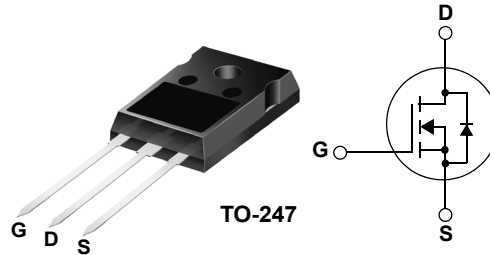
SuperFET™ is Fairchild's proprietary new generation of high voltage MOSFETs utilizing an advanced charge balance mechanism for outstanding low on-resistance and lower gate charge performance.

This advanced technology has been tailored to minimize conduction loss, provide superior switching performance, and withstand extreme dv/dt rate and higher avalanche energy.

Consequently, SuperFET is suitable for various automotive DC/DC power conversion.

Applications

- Automotive On Board Charger
- Automotive DC/DC converter for HEV



For current package drawing, please refer to the Fairchild website at www.fairchildsemi.com/packaging



MOSFET Maximum Ratings $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Rated Value	Units
V_{DSS}	Drain to Source Voltage		600	V
V_{GS}	Gate to Source Voltage		±30	V
I_D	Drain Current - Continuous ($V_{GS}=10$) (Note 1)	$T_C = 25^\circ\text{C}$	47	A
	Pulsed Drain Current	$T_C = 25^\circ\text{C}$	See Figure4	
E_{AS}	Single Pulse Avalanche Energy	(Note 2)	810	mJ
P_D	Power Dissipation		417	W
	Derate above 25°C		3.3	W/ $^\circ\text{C}$
T_J, T_{STG}	Operating and Storage Temperature		-55 to + 150	$^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance Junction to Case		0.3	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	50	$^\circ\text{C}/\text{W}$

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FCH47N60F	FCH47N60F_F085	TO-247	-	-	30 units

Notes:

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^\circ\text{C}$, $L = 5\text{mH}$, $I_{AS} = 18\text{A}$, $V_{DD} = 100\text{V}$ during inductor charging and $V_{DD} = 0\text{V}$ during time in avalanche

3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

$B_{V_{DS}}$	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}, V_{GS} = 0\text{V}$	600	-	-	V
I_{DSS}	Drain to Source Leakage Current	$V_{DS} = 600\text{V}, T_J = 25^\circ\text{C}$	-	-	10	μA
		$V_{GS} = 0\text{V}, T_J = 150^\circ\text{C}(\text{Note 4})$	-	-	1	mA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 30\text{V}$	-	-	± 100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu\text{A}$	3.0	4.0	5.0	V
$r_{DS(on)}$	Drain to Source On Resistance	$I_D = 47\text{A}, T_J = 25^\circ\text{C}$	-	66	75	$\text{m}\Omega$
		$V_{GS} = 10\text{V}, T_J = 150^\circ\text{C}(\text{Note 4})$	-	180	223	$\text{m}\Omega$

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$	-	5900	8000	pF
C_{oss}	Output Capacitance		-	3200	4200	pF
C_{rss}	Reverse Transfer Capacitance		-	250	-	pF
R_g	Gate Resistance	$f = 1\text{MHz}$	-	1	-	Ω
$Q_{g(ToT)}$	Total Gate Charge at 10V	$V_{GS} = 0$ to 10V	-	190	250	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0$ to 2V				
Q_{gs}	Gate to Source Gate Charge	$V_{DD} = 300\text{V}, I_D = 47\text{A}$	-	40	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		-	96	-	nC

Switching Characteristics

t_{on}	Turn-On Time	$V_{DD} = 300\text{V}, I_D = 47\text{A}, V_{GS} = 10\text{V}, R_G = 25\Omega$	-	-	410	ns
$t_{d(on)}$	Turn-On Delay Time		-	110	-	ns
t_r	Rise Time		-	160	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	540	-	ns
t_f	Fall Time		-	125	-	ns
t_{off}	Turn-Off Time		-	-	1000	ns

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Voltage	$I_{SD} = 47\text{A}, V_{GS} = 0\text{V}$	-	-	1.4	V
		$I_{SD} = 23.5\text{A}, V_{GS} = 0\text{V}$	-	-	1.25	V
T_{rr}	Reverse Recovery Time	$I_F = 47\text{A}, dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	207	350	ns
Q_{rr}	Reverse Recovery Charge	$V_{DD} = 480\text{V}$	-	2.0	3.6	μC

Notes:

4: The maximum value is specified by design at $T_J = 150^\circ\text{C}$. Product is not tested to this condition in production.

Typical Characteristics

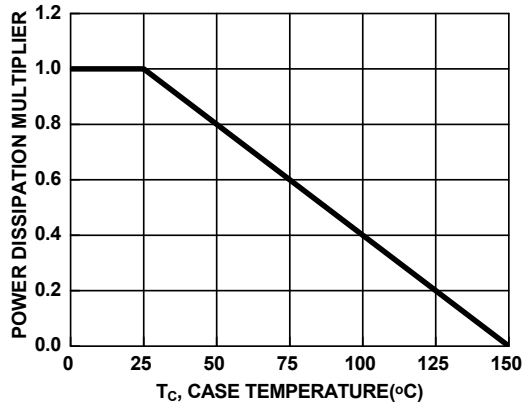


Figure 1. Normalized Power Dissipation vs Case Temperature

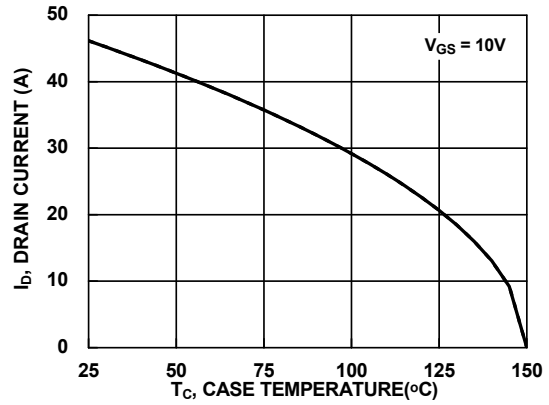


Figure 2. Maximum Continuous Drain Current vs Case Temperature

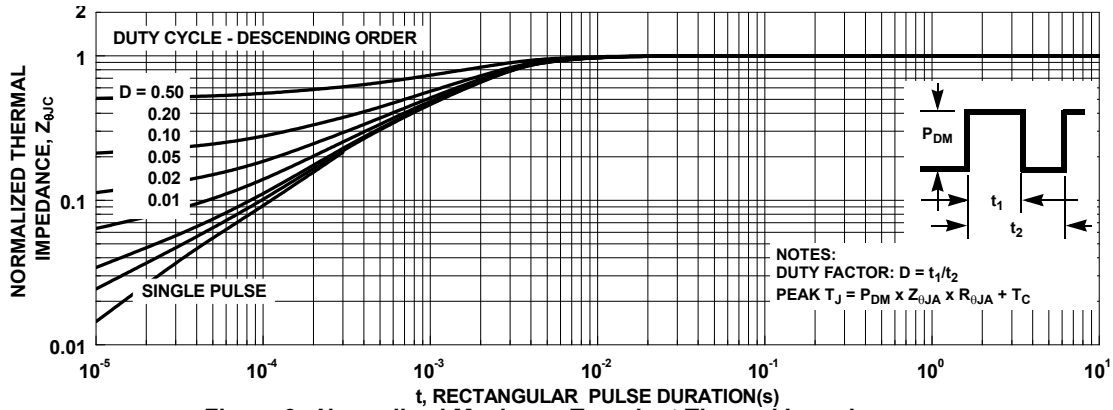


Figure 3. Normalized Maximum Transient Thermal Impedance

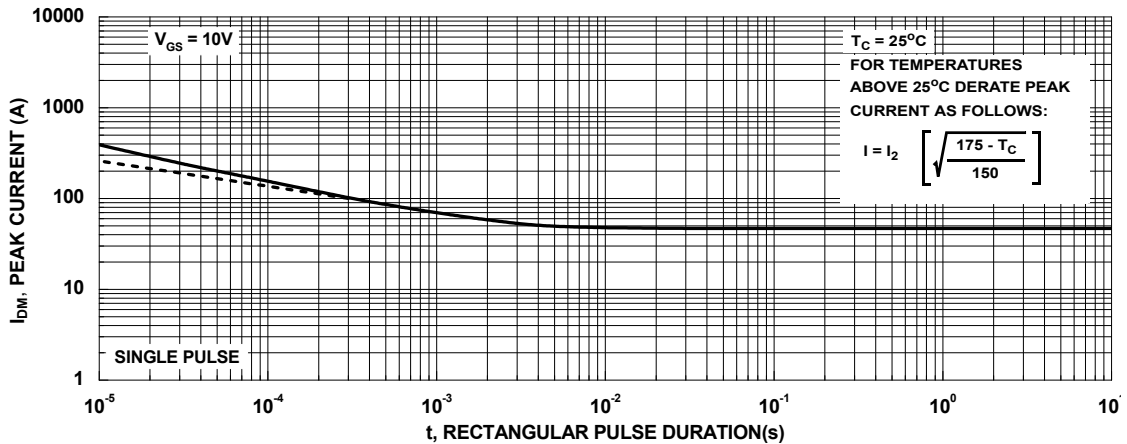


Figure 4. Peak Current Capability

Typical Characteristics

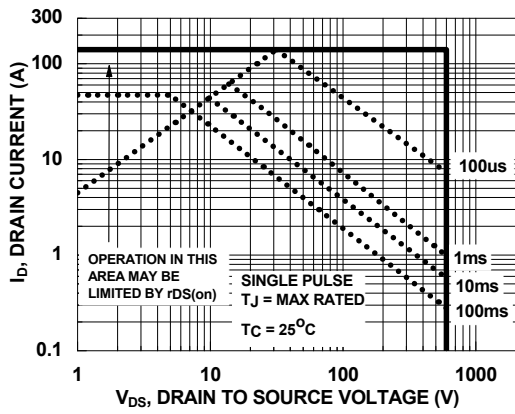


Figure 5. Forward Bias Safe Operating Area

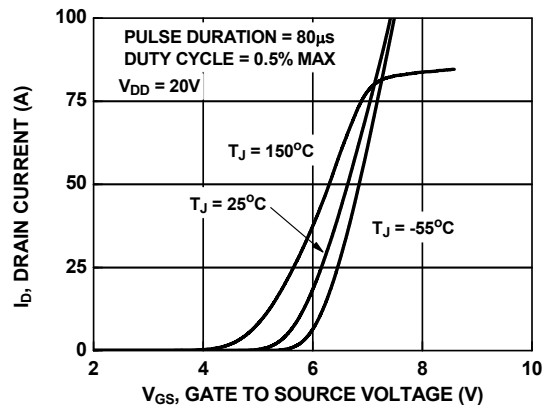


Figure 6. Transfer Characteristics

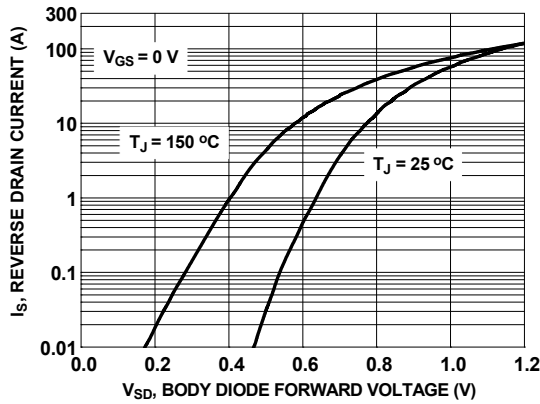


Figure 7. Forward Diode Characteristics

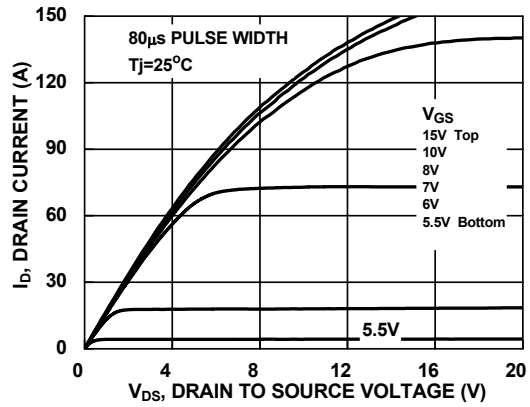


Figure 8. Saturation Characteristics

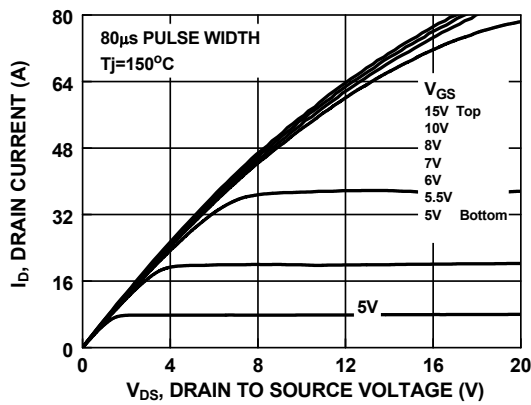


Figure 9. Saturation Characteristics

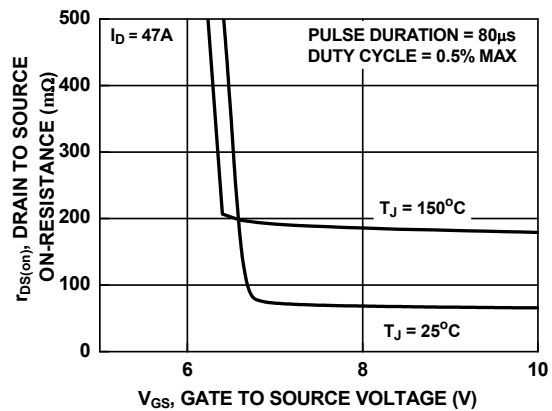


Figure 10. Rdson vs Gate Voltage

Typical Characteristics

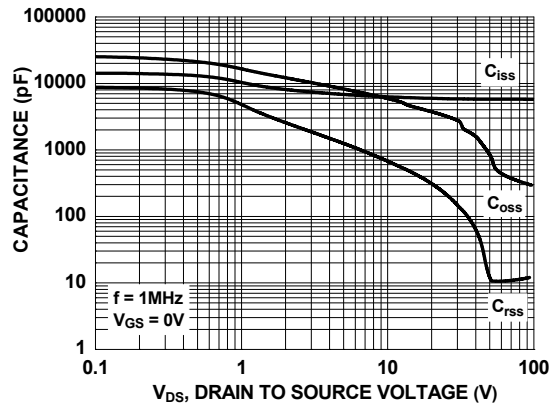
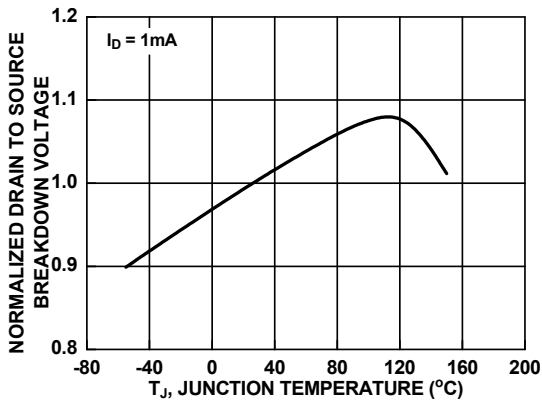
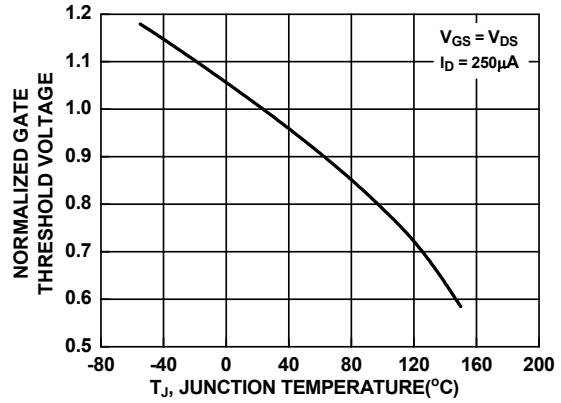
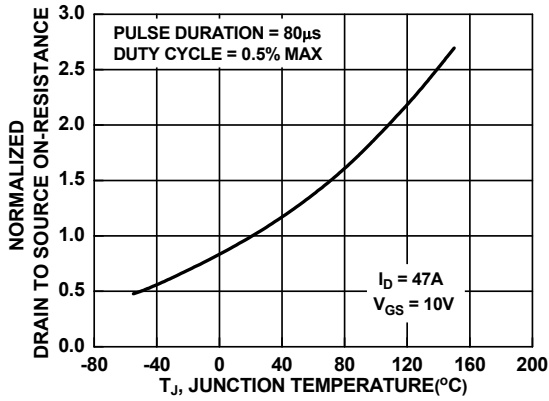


Figure 13. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

Figure 14. Capacitance vs Drain to Source Voltage

Figure 16.

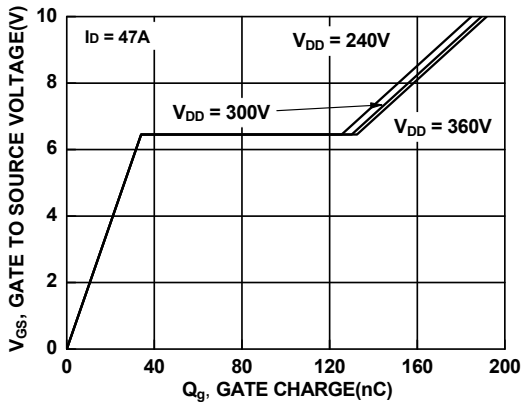





Figure 15. Gate Charge vs Gate to Source Voltage



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